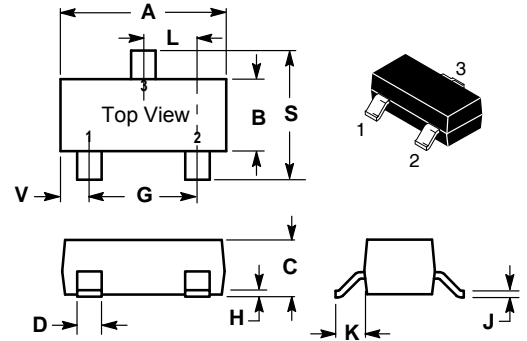
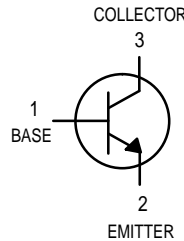


RoHS Compliant Product

A suffix of "-C" specifies halogen & lead-free

**FEATURES**

- Epitaxial Planar Die Construction
- Complementary PNP Type Available (MMBT2907A)
- Ideal for Medium Power Amplification and Switching



**MAXIMUM RATINGS**

| Rating                         | Symbol    | 2222 | 2222A | Unit |
|--------------------------------|-----------|------|-------|------|
| Collector–Emitter Voltage      | $V_{CEO}$ | 30   | 40    | Vdc  |
| Collector–Base Voltage         | $V_{CBO}$ | 60   | 75    | Vdc  |
| Emitter–Base Voltage           | $V_{EBO}$ | 5.0  | 6.0   | Vdc  |
| Collector Current — Continuous | $I_C$     | 600  |       | mAdc |

| SOT-23              |       |       |
|---------------------|-------|-------|
| Dim                 | Min   | Max   |
| A                   | 2.800 | 3.040 |
| B                   | 1.200 | 1.400 |
| C                   | 0.890 | 1.110 |
| D                   | 0.370 | 0.500 |
| G                   | 1.780 | 2.040 |
| H                   | 0.013 | 0.100 |
| J                   | 0.085 | 0.177 |
| K                   | 0.450 | 0.600 |
| L                   | 0.890 | 1.020 |
| S                   | 2.100 | 2.500 |
| V                   | 0.450 | 0.600 |
| All Dimension in mm |       |       |

**THERMAL CHARACTERISTICS**

| Characteristic  | Symbol          | Max         | Unit  |
|---|-----------------|-------------|-------|
| Total Device Dissipation FR–5 Board <sup>(1)</sup><br>$T_A = 25^\circ\text{C}$<br>Derate above $25^\circ\text{C}$         | $P_D$           | 225         | mW    |
|   |                 | 1.8         | mW/°C |
| Thermal Resistance, Junction to Ambient   | $R_{\theta JA}$ | 556         | °C/W  |
| Total Device Dissipation<br>Alumina Substrate, <sup>(2)</sup> $T_A = 25^\circ\text{C}$<br>Derate above $25^\circ\text{C}$ | $P_D$           | 300         | mW    |
|   |                 | 2.4         | mW/°C |
| Thermal Resistance, Junction to Ambient   | $R_{\theta JA}$ | 417         | °C/W  |
| Junction and Storage Temperature  | $T_J, T_{stg}$  | –55 to +150 | °C    |

**DEVICE MARKING**

|                                |
|--------------------------------|
| MMBT2222 = M1B; MMBT2222A = 1P |
|--------------------------------|

**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

| Characteristic | Symbol | Min | Max | Unit |
|----------------|--------|-----|-----|------|
|----------------|--------|-----|-----|------|

**OFF CHARACTERISTICS**

|   |  |               |                  |                          |                 |
|---|--|---------------|------------------|--------------------------|-----------------|
| Collector–Emitter Breakdown Voltage ( $I_C = 10 \text{ mAdc}, I_B = 0$ )  | MMBT2222<br>MMBT2222A                          | $V_{(BR)CEO}$ | 30<br>40         | —<br>—                   | Vdc             |
| Collector–Base Breakdown Voltage ( $I_C = 10 \mu\text{Adc}, I_E = 0$ )  | MMBT2222<br>MMBT2222A                          | $V_{(BR)CBO}$ | 60<br>75         | —<br>—                   | Vdc             |
| Emitter–Base Breakdown Voltage ( $I_E = 10 \mu\text{Adc}, I_C = 0$ )  | MMBT2222<br>MMBT2222A                          | $V_{(BR)EBO}$ | 5.0<br>6.0       | —<br>—                   | Vdc             |
| Collector Cutoff Current ( $V_{CE} = 60 \text{ Vdc}, V_{EB(off)} = 3.0 \text{ Vdc}$ )   | MMBT2222A                                      | $I_{CEX}$     | —                | 10                       | nAdc            |
| Collector Cutoff Current ( $V_{CB} = 50 \text{ Vdc}, I_E = 0$ )<br>( $V_{CB} = 60 \text{ Vdc}, I_E = 0$ )<br>( $V_{CB} = 50 \text{ Vdc}, I_E = 0, T_A = 125^\circ\text{C}$ )<br>( $V_{CB} = 60 \text{ Vdc}, I_E = 0, T_A = 125^\circ\text{C}$ ) | MMBT2222<br>MMBT2222A<br>MMBT2222<br>MMBT2222A | $I_{CBO}$     | —<br>—<br>—<br>— | 0.01<br>0.01<br>10<br>10 | $\mu\text{Adc}$ |
| Emitter Cutoff Current ( $V_{EB} = 3.0 \text{ Vdc}, I_C = 0$ )  | MMBT2222A                                      | $I_{EBO}$     | —                | 100                      | nAdc            |
| Base Cutoff Current ( $V_{CE} = 60 \text{ Vdc}, V_{EB(off)} = 3.0 \text{ Vdc}$ )  | MMBT2222A                                      | $I_{BL}$      | —                | 20                       | nAdc            |

1. FR±5 = 1.0 x 0.75 x 0.062 in.

2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.

REM : Thermal Clad is a trademark of the Bergquist Company.

**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted) (Continued)

| Characteristic   | Symbol        | Min   | Max                                    | Unit |
|--|---------------|---|--|------|
| <b>ON CHARACTERISTICS</b>  |               |   |  |      |
| DC Current Gain<br>( $I_C = 0.1 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ )<br>( $I_C = 1.0 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ )<br>( $I_C = 10 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ )<br>( $I_C = 10 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , $T_A = -55^\circ\text{C}$ )<br>( $I_C = 150 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ ) (3)<br>( $I_C = 150 \text{ mAdc}$ , $V_{CE} = 1.0 \text{ Vdc}$ ) (3)<br>( $I_C = 500 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ ) (3) | $h_{FE}$      | 35<br>50<br>75<br>35<br>100<br>50<br>30<br>40 | —<br>—<br>—<br>—<br>300<br>—<br>—<br>— | —    |
| Collector–Emitter Saturation Voltage (3)<br>( $I_C = 150 \text{ mAdc}$ , $I_B = 15 \text{ mAdc}$ )<br><br>( $I_C = 500 \text{ mAdc}$ , $I_B = 50 \text{ mAdc}$ )   | $V_{CE(sat)}$ | —<br>—<br>—<br>—                              | 0.4<br>0.3<br>1.6<br>1.0               | Vdc  |
| Base–Emitter Saturation Voltage (3)<br>( $I_C = 150 \text{ mAdc}$ , $I_B = 15 \text{ mAdc}$ )<br><br>( $I_C = 500 \text{ mAdc}$ , $I_B = 50 \text{ mAdc}$ )  | $V_{BE(sat)}$ | —<br>0.6<br>—<br>—                            | 1.3<br>1.2<br>2.6<br>2.0               | Vdc  |

**SMALL–SIGNAL CHARACTERISTICS**

|  |            |             |             |                  |
|--|------------|-------------|-------------|------------------|
| Current–Gain — Bandwidth Product (4)<br>( $I_C = 20 \text{ mAdc}$ , $V_{CE} = 20 \text{ Vdc}$ , $f = 100 \text{ MHz}$ )  | $f_T$      | 250<br>300  | —<br>—      | MHz              |
| Output Capacitance<br>( $V_{CB} = 10 \text{ Vdc}$ , $I_E = 0$ , $f = 1.0 \text{ MHz}$ )  | $C_{obo}$  | —           | 8.0         | pF               |
| Input Capacitance<br>( $V_{EB} = 0.5 \text{ Vdc}$ , $I_C = 0$ , $f = 1.0 \text{ MHz}$ )  | $C_{ibo}$  | —<br>—      | 30<br>25    | pF               |
| Input Impedance<br>( $I_C = 1.0 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 1.0 \text{ kHz}$ )<br>( $I_C = 10 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 1.0 \text{ kHz}$ )           | $h_{ie}$   | 2.0<br>0.25 | 8.0<br>1.25 | k $\Omega$       |
| Voltage Feedback Ratio<br>( $I_C = 1.0 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 1.0 \text{ kHz}$ )<br>( $I_C = 10 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 1.0 \text{ kHz}$ )    | $h_{re}$   | —<br>—      | 8.0<br>4.0  | $\times 10^{-4}$ |
| Small–Signal Current Gain<br>( $I_C = 1.0 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 1.0 \text{ kHz}$ )<br>( $I_C = 10 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 1.0 \text{ kHz}$ ) | $h_{fe}$   | 50<br>75    | 300<br>375  | —                |
| Output Admittance<br>( $I_C = 1.0 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 1.0 \text{ kHz}$ )<br>( $I_C = 10 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 1.0 \text{ kHz}$ )         | $h_{oe}$   | 5.0<br>25   | 35<br>200   | $\mu\text{mhos}$ |
| Collector Base Time Constant<br>( $I_E = 20 \text{ mAdc}$ , $V_{CB} = 20 \text{ Vdc}$ , $f = 31.8 \text{ MHz}$ )   | $r_b, C_C$ | —           | 150         | ps               |
| Noise Figure<br>( $I_C = 100 \mu\text{Adc}$ , $V_{CE} = 10 \text{ Vdc}$ , $R_S = 1.0 \text{ k}\Omega$ , $f = 1.0 \text{ kHz}$ )  | NF         | —           | 4.0         | dB               |

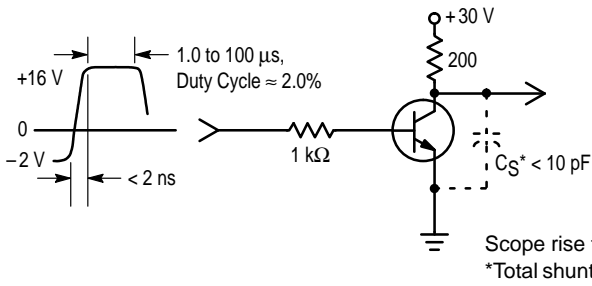
**SWITCHING CHARACTERISTICS (MMBT2222A only)**

|              |   |       |   |     |    |
|--------------|---|-------|---|-----|----|
| Delay Time   | ( $V_{CC} = 30 \text{ Vdc}$ , $V_{BE(off)} = -0.5 \text{ Vdc}$ ,<br>$I_C = 150 \text{ mAdc}$ , $I_{B1} = 15 \text{ mAdc}$ ) | $t_d$ | — | 10  | ns |
| Rise Time    |   | $t_r$ | — | 25  |    |
| Storage Time | ( $V_{CC} = 30 \text{ Vdc}$ , $I_C = 150 \text{ mAdc}$ ,<br>$I_{B1} = I_{B2} = 15 \text{ mAdc}$ )                           | $t_s$ | — | 225 | ns |
| Fall Time    |   | $t_f$ | — | 60  |    |

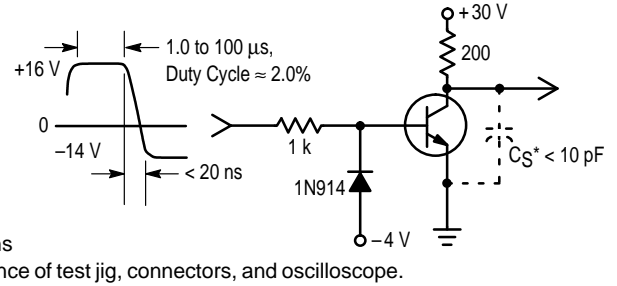
3. Pulse Test: Pulse Width  $\leq 300 \mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

4.  $f_T$  is defined as the frequency at which  $|h_{fe}|$  extrapolates to unity.

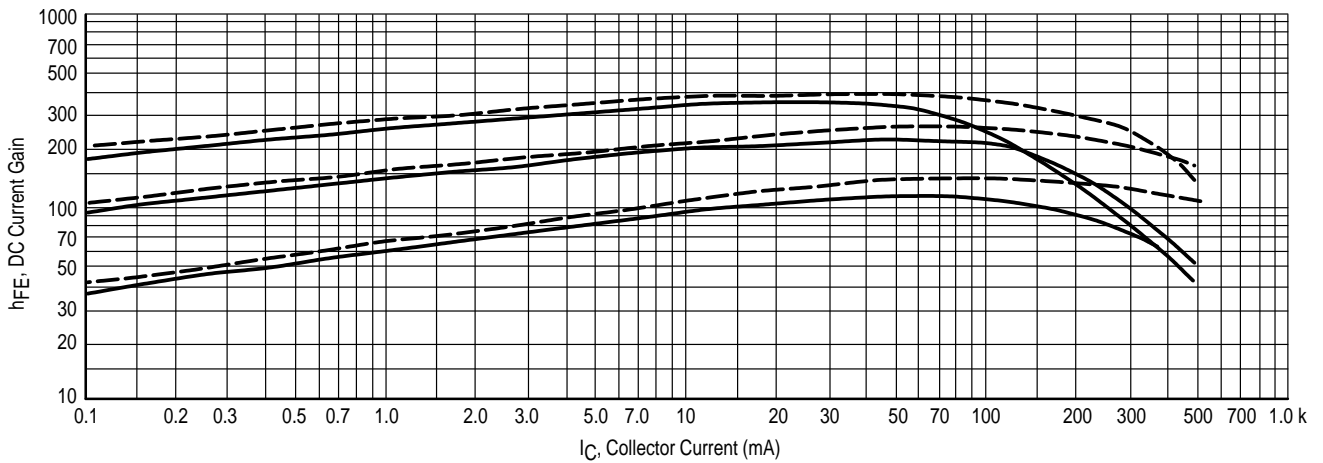
**SWITCHING TIME EQUIVALENT TEST CIRCUITS**



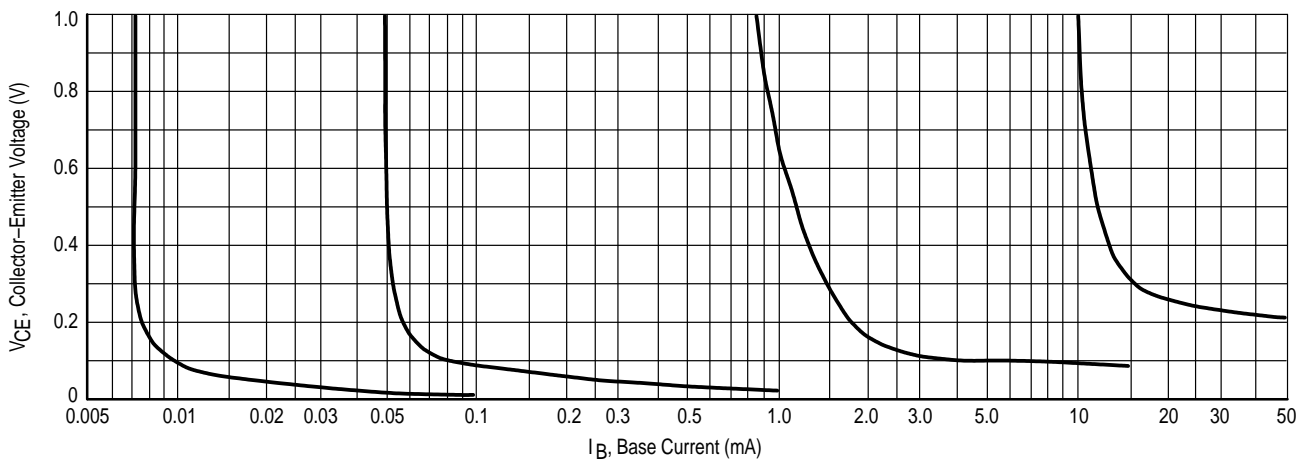
**Figure 1. Turn-On Time**



**Figure 2. Turn-Off Time**



**Figure 3. DC Current Gain**



**Figure 4. Collector Saturation Region**

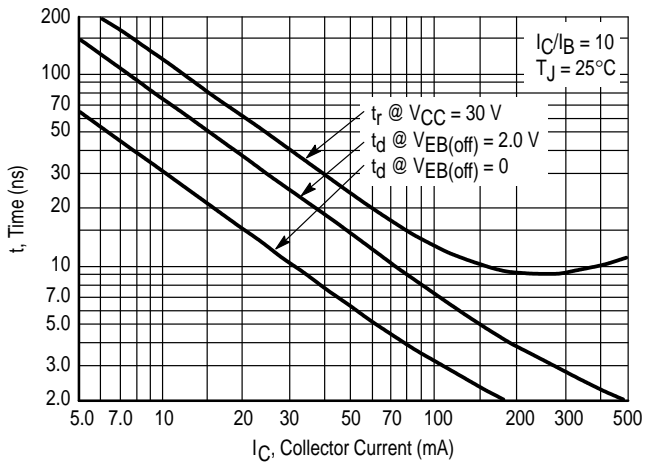


Figure 5. Turn-On Time

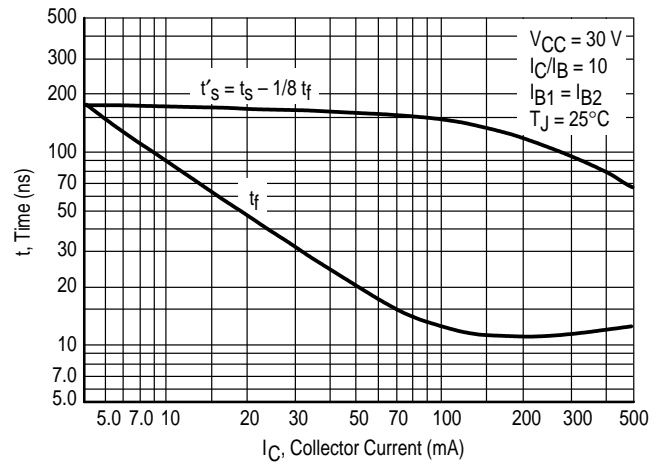


Figure 6. Turn-Off Time

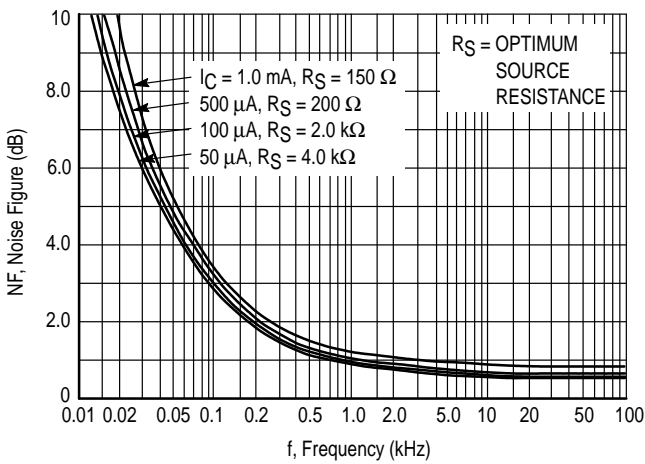


Figure 7. Frequency Effects

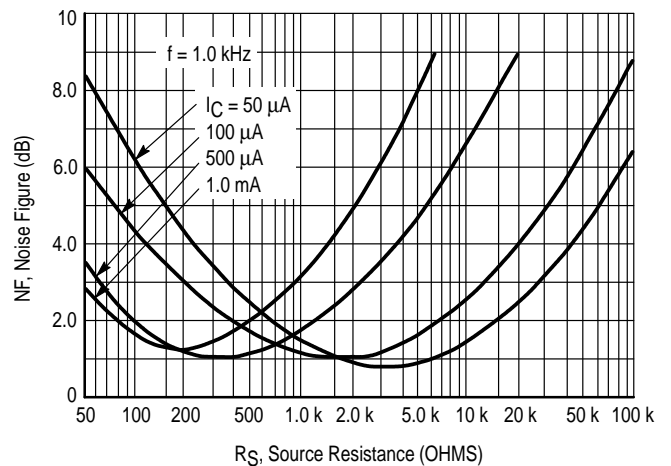


Figure 8. Source Resistance Effects

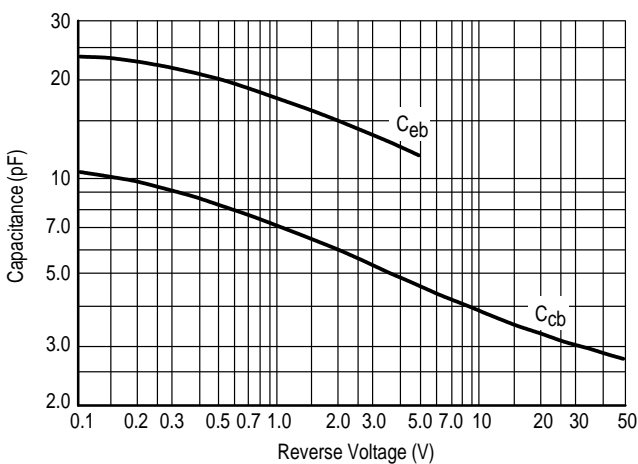


Figure 9. Capacitances

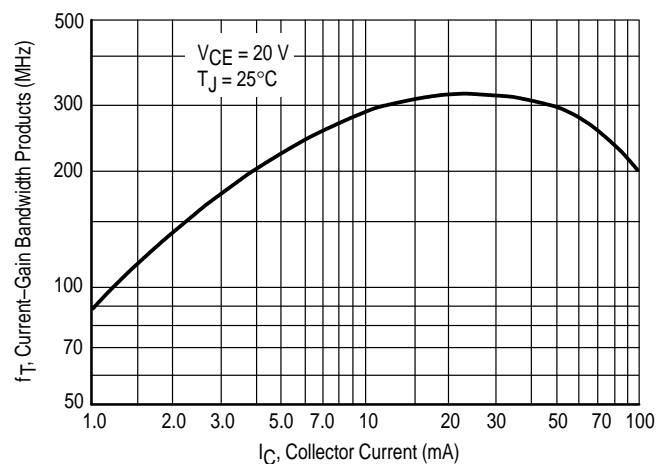


Figure 10. Current-Gain Bandwidth Product

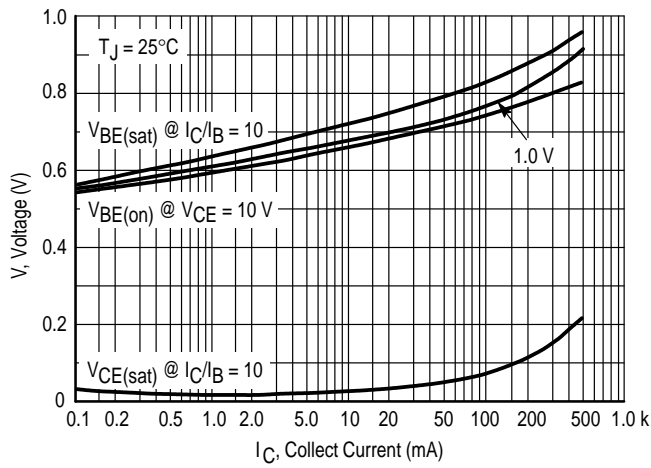


Figure 11. "On" Voltages

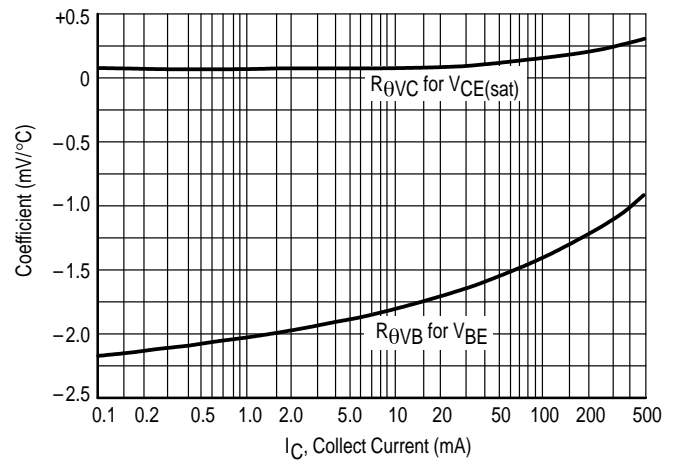


Figure 12. Temperature Coefficients